

CMOS Expandable 4-Wide 2-Input AND-OR-INVERT Gate

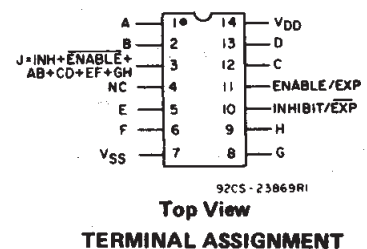
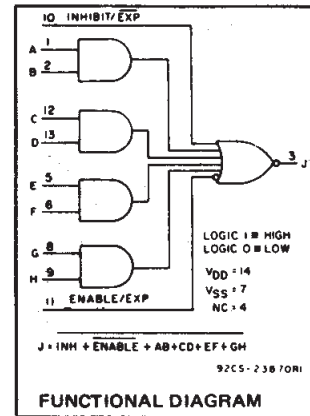
High-Voltage Types (20-Volt Rating)

■ CD4086B contains one 4-wide 2-input AND-OR-INVERT gate with an INHIBIT/EXP input and an ENABLE/EXP input. For a 4-wide A-O-I function INHIBIT/EXP is tied to V_{SS} and ENABLE/EXP to V_{DD} . See Fig.10 and its associated explanation for applications where a capability greater than 4-wide is required.

The CD4086B is supplied in 14-lead dual-in-line ceramic packages (D and F suffixes), 14-lead dual-in-line plastic packages (E suffix), and in chip form (H suffix).

Features:

- Medium-speed operation — $t_{PHL} = 90$ ns;
 $t_{PLH} = 140$ ns (typ.) at 10 V
- INHIBIT and ENABLE inputs
- Buffered outputs
- 100% tested for quiescent current at 20 V
- Maximum input leakage current of 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package temperature range):
1 V at $V_{DD} = 5$ V
2 V at $V_{DD} = 10$ V
2.5 V at $V_{DD} = 15$ V
- Standardized, symmetrical output characteristics
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"



Top View
TERMINAL ASSIGNMENT

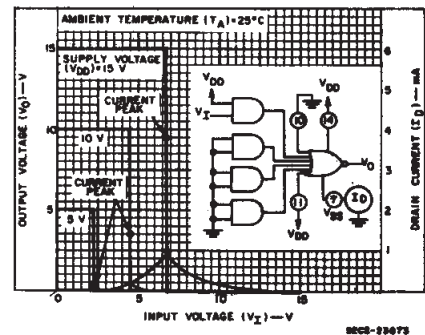


Fig. 1 — Typical voltage and current transfer characteristics.

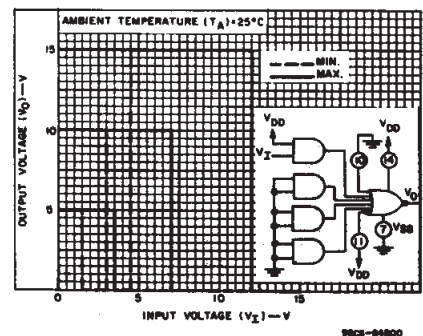


Fig. 2 — Minimum and maximum voltage transfer characteristics.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V_{DD})	 -0.5V to +20V
Voltages referenced to V_{SS} Terminal)	 -0.5V to $V_{DD} + 0.5$ V
INPUT VOLTAGE RANGE, ALL INPUTS	 -0.5V to $V_{DD} + 0.5$ V
DC INPUT CURRENT, ANY ONE INPUT	 ± 10 mA
POWER DISSIPATION PER PACKAGE (P_D):	 500 mW
For $T_A = -55^\circ\text{C}$ to $+100^\circ\text{C}$	 Derate Linearly at 12 mW/ $^\circ\text{C}$ to 200 mW
For $T_A = +100^\circ\text{C}$ to $+125^\circ\text{C}$	
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	 100 mW
FOR $T_A =$ FULL PACKAGE-TEMPERATURE RANGE (All Package Types)	 -55°C to $+125^\circ\text{C}$
OPERATING-TEMPERATURE RANGE (T_A)	 -65°C to $+150^\circ\text{C}$
STORAGE-TEMPERATURE RANGE (T_{stg})	
LEAD TEMPERATURE (DURING SOLDERING):	 +265°C
At distance 1/16 $\pm$ 1/32 Inch (1.59 $\pm$ 0.79 mm) from case for 10s max	

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIMITS		UNITS
	MIN.	MAX.	
Supply-Voltage Range (For $T_A =$ Full Package-Temperature Range)	3	18	V

CD4086B Types

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
	V _O (V)	V _{IN} (V)	V _{DD} (V)	-55	-40	+85	+125	+25			
								Min.	Typ.	Max.	
Quiescent Device Current I _{DD} Max.	—	0,5	5	1	1	30	30	—	0.02	1	μA
	—	0,10	10	2	2	60	60	—	0.02	2	
	—	0,15	15	4	4	120	120	—	0.02	4	
	—	0,20	20	20	20	600	600	—	0.04	20	
Output Low (Sink) Current, I _{OL} Min.	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	—	mA
	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	—	
	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	—	
	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	—	
Output High (Source) Current, I _{OH} Min.	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	—	mA
	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	—	
	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	—	
	—	—	—	—	—	—	—	—	—	—	
Output Voltage: Low-Level, V _{OL} Max.	—	0,5	5	0.05				—	0	0.05	V
—	0,10	10	0.05				—	0	0.05		
—	0,15	15	0.05				—	0	0.05		
Output Voltage: High-Level, V _{OH} Min.	—	0,5	5	4.95				4.95	5	—	V
—	0,10	10	9.95				9.95	10	—		
—	0,15	15	14.95				14.95	15	—		
Input Low Voltage, V _{IL} Max.	0.5,4.5	—	5	1.5				—	—	1.5	V
	1,9	—	10	3				—	—	3	
	1.5,13.5	—	15	4				—	—	4	
Input High Voltage, V _{IH} Min.	0.5,4.5	—	5	3.5				3.5	—	—	V
	1,9	—	10	7				7	—	—	
	1.5,13.5	—	15	11				11	—	—	
Input Current, I _{IN} Max.	—	0,18	18	±0.1	±0.1	±1	±1	—	±10 ⁻⁵	±0.1	μA

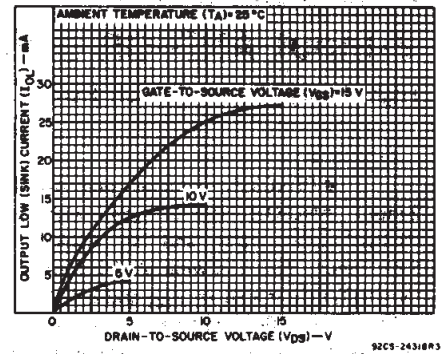


Fig. 3 - Typical output low (sink) current characteristics.

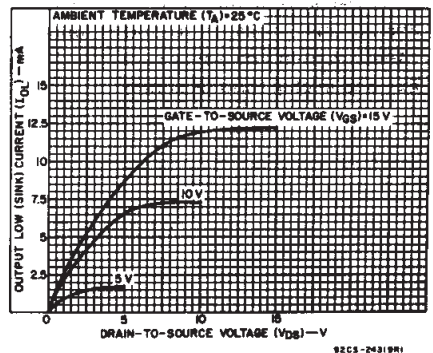


Fig. 4 - Minimum output low (sink) current characteristics.

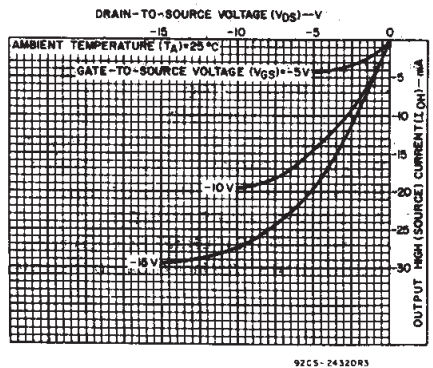


Fig. 5 - Typical output high (source) current characteristics.

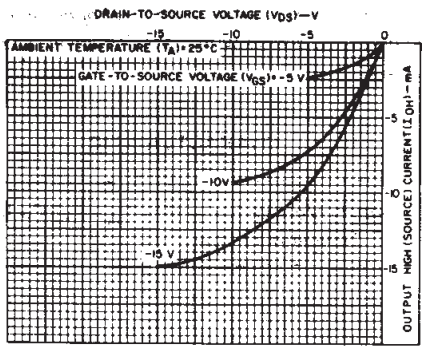


Fig. 8 - Minimum output high (source) current characteristics.

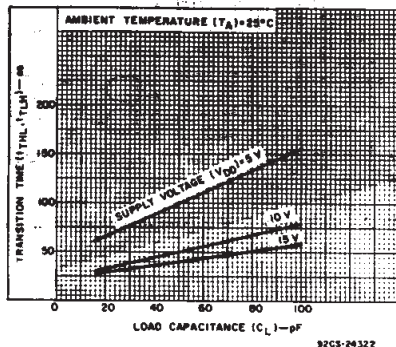


Fig. 6 - Typical transition time vs. load capacitance.

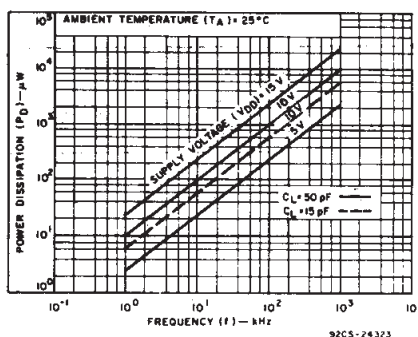


Fig. 7 - Typical power dissipation vs. frequency.

CD4086B Types

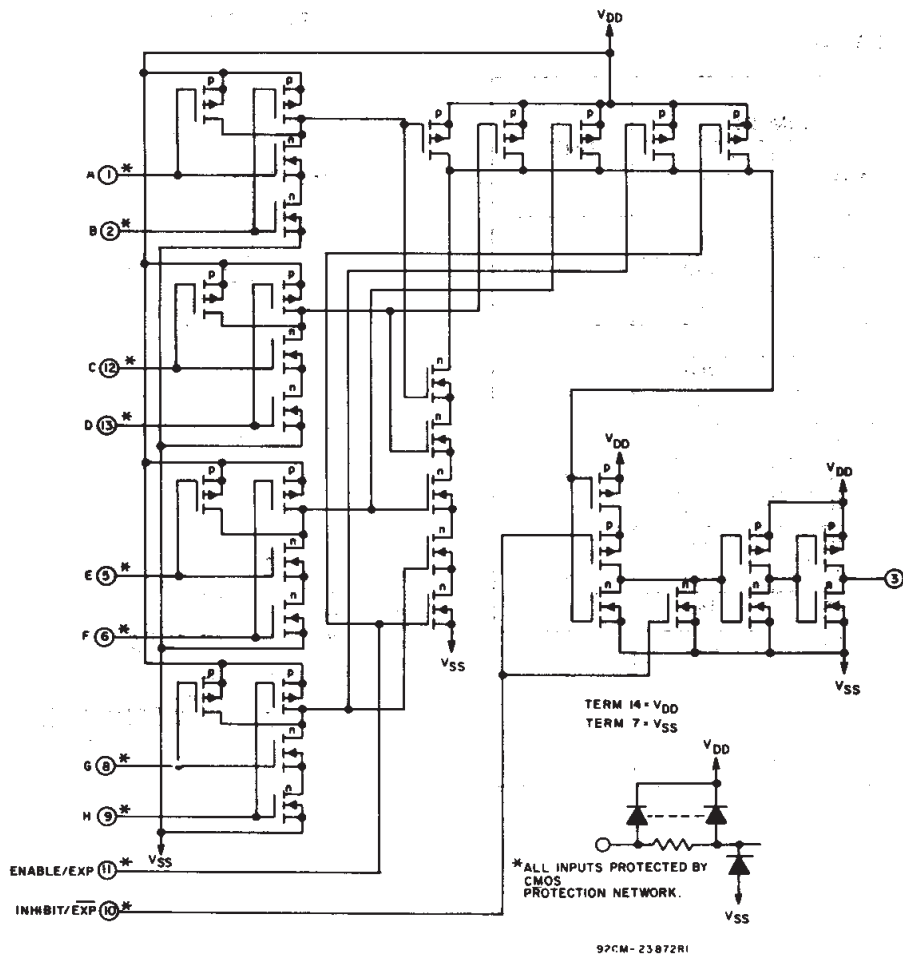


Fig. 9 - CD4086B schematic diagram.

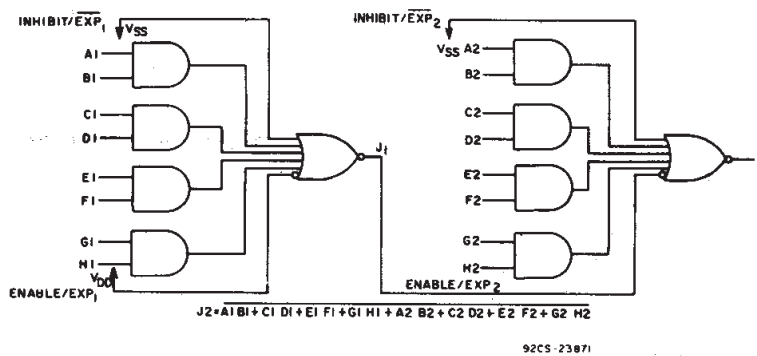


Fig. 10 - Two CD4086's connected as an 8-wide 2-input A-O-I gate.

Fig. 10 above shows two CD4086's utilized to obtain an 8-wide 2-input A-O-I function. The output (J1) of one CD4086 is fed directly to the ENABLE/EXP2 line of the second CD4086. In a similar fashion, any

NAND gate output can be fed directly into the ENABLE/EXP input to obtain a 5-wide A-O-I function. In addition, any AND gate output can be fed directly into the INHIBIT/EXP input with the same result.

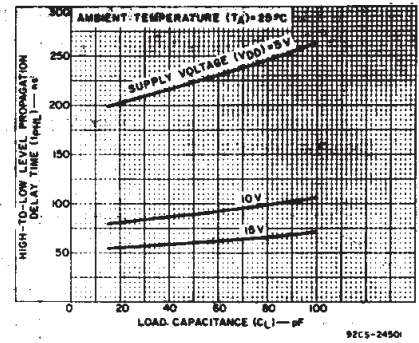


Fig. 11 - Typical DATA or ENABLE high-to-low level propagation delay time vs. load capacitance.

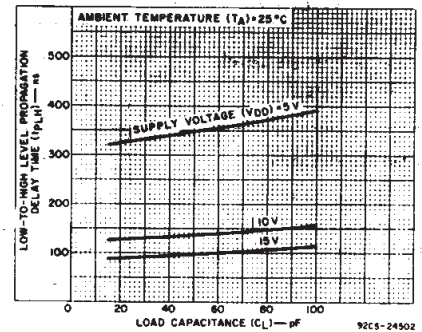


Fig. 12 - Typical DATA or ENABLE low-to-high level propagation delay time vs. load capacitance.

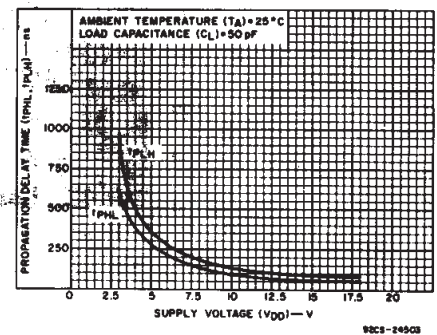


Fig. 13 - Typical DATA or ENABLE propagation delay time vs. supply voltage.

CD4086B Types

DYNAMIC ELECTRICAL CHARACTERISTICS

At $T_A = 25^\circ\text{C}$; Input $t_r, t_f = 20\text{ ns}$, $C_L = 50\text{ pF}$, $R_L = 200\text{ k}\Omega$

CHARACTERISTIC	CONDITIONS	LIMITS		UNITS
		V_{DD} (V)	TYP.	MAX.
Propagation Delay Time (Data): High-to-Low Level, t_{PHL}		5	225	450
		10	90	180
		15	60	120
Low-to-High Level, t_{PLH}		5	310	620
		10	125	250
		15	90	180
Propagation Delay Time (Inhibit): High-to-Low Level, $t_{PHL}(\text{INH})$		5	150	300
		10	60	120
		15	40	80
Low-to-High Level, $t_{PLH}(\text{INH})$		5	250	500
		10	100	200
		15	70	140
Transition Time, t_{THL}, t_{TLH}		5	100	200
		10	50	100
		15	40	80
Input Capacitance C_{IN}	Any Input		5	7.5
				pF

TEST CIRCUITS

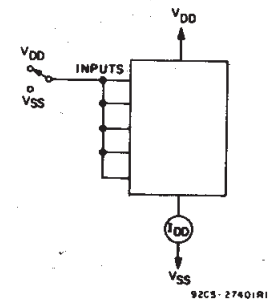


Fig. 14 - Quiescent device current.

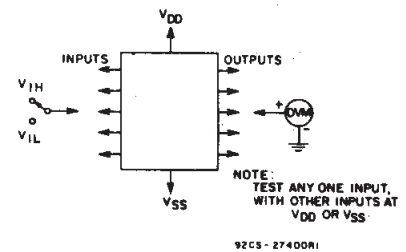


Fig. 15 - Input voltage.

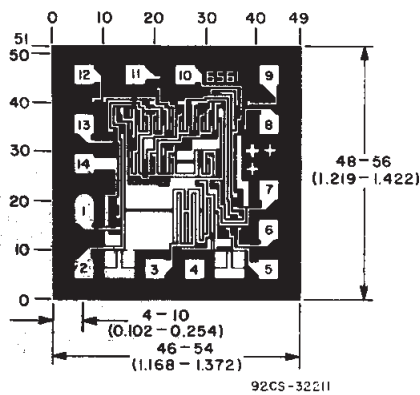


Fig. 16 - Input leakage current.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

Dimensions and Pad Layout for the CD4086BH

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